

# BAV19WS-V-G, BAV20WS-V-G, BAV21WS-V-G

**Vishay Semiconductors** 

## **Small Signal Switching Diodes, High Voltage**

#### **Features**

- · Silicon epitaxial planar diodes
- · For general purpose
- · AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





#### **Mechanical Data**

Case: SOD-323 Weight: approx. 4 mg

#### Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

#### **Parts Table**

| Part        | Type differentiation   | Ordering code                    | Type Marking | Remarks       |
|-------------|------------------------|----------------------------------|--------------|---------------|
| BAV19WS-V-G | V <sub>R</sub> = 100 V | BAV19WS-V-G-18 or BAV19WS-V-G-08 | AS           | Tape and reel |
| BAV20WS-V-G | V <sub>R</sub> = 150 V | BAV20WS-V-G-18 or BAV20WS-V-G-08 | AT           | Tape and reel |
| BAV21WS-V-G | V <sub>R</sub> = 200 V | BAV21WS-V-G-18 or BAV21WS-V-G-08 | AU           | Tape and reel |

### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter   | Test condition                                | Part        | Symbol             | Value             | Unit |
|---|---|-------------|--------------------|-------------------|------|
|   |   | BAV19WS-V-G | V <sub>R</sub>     | 100               | V    |
| Continuous reverse voltage  |   | BAV20WS-V-G | V <sub>R</sub>     | 150               | V    |
|   |   | BAV21WS-V-G | V <sub>R</sub>     | 200               | V    |
|   |   | BAV19WS-V-G | V <sub>RRM</sub>   | 120               | V    |
| Repetitive peak reverse voltage                                       |   | BAV20WS-V-G | V <sub>RRM</sub>   | 200               | V    |
|   |   | BAV21WS-V-G | V <sub>RRM</sub>   | 250               | V    |
| Forward continuous current  |   |             | I <sub>F</sub>     | 250 <sup>1)</sup> | mA   |
| Rectified current (average) half wave rectification with resist. load |   |             | I <sub>F(AV)</sub> | 200 <sup>1)</sup> | mA   |
| Repetitive peak forward current                                       | $f \ge 50 \text{ Hz}, \ \theta = 180^{\circ}$ |             | I <sub>FRM</sub>   | 625 <sup>1)</sup> | mA   |
| Surge forward current   | t < 1 s, T <sub>j</sub> = 25 °C               |             | I <sub>FSM</sub>   | 1                 | Α    |
| Power dissipation   |   |             | P <sub>tot</sub>   | 200 <sup>1)</sup> | mW   |

#### Note

<sup>1)</sup> Valid provided that leads are kept at ambient temperature

<sup>\*\*</sup> Please see document "Vishay Material Category Policy": <a href="www.vishay.com/doc?99902">www.vishay.com/doc?99902</a>

# BAV19WS-V-G, BAV20WS-V-G, BAV21WS-V-G

### **Vishay Semiconductors**



#### **Thermal Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter                                  | Test condition | Symbol           | Value                       | Unit |  |
|--|----------------|------------------|-----------------------------|------|--|
| Thermal resistance junction to ambient air |                | $R_{thJA}$       | 650 <sup>1)</sup>           | K/W  |  |
| Junction temperature                       |                | T <sub>j</sub>   | 150 <sup>1)</sup>           | °C   |  |
| Storage temperature range                  |                | T <sub>stg</sub> | - 65 to + 150 <sup>1)</sup> | °C   |  |

#### Note

#### **Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

| Parameter                  | Test condition  | Part        | Symbol          | Min. | Тур. | Max. | Unit |
|----------------------------|---|-------------|-----------------|------|------|------|------|
| Forward voltage            | I <sub>F</sub> = 100 mA   |             | V <sub>F</sub>  |      |      | 1    | V    |
|                            | I <sub>F</sub> = 200 mA   |             | V <sub>F</sub>  |      |      | 1.25 | V    |
| Leakage current            | V <sub>R</sub> = 100 V  | BAV19WS-V-G | I <sub>R</sub>  |      |      | 100  | nA   |
|                            | $V_R = 100 \text{ V}, T_j = 100 ^{\circ}\text{C}$                                     | BAV19WS-V-G | I <sub>R</sub>  |      |      | 15   | μΑ   |
|                            | V <sub>R</sub> = 150 V  | BAV20WS-V-G | I <sub>R</sub>  |      |      | 100  | nA   |
|                            | $V_R = 150 \text{ V}, T_j = 100 ^{\circ}\text{C}$                                     | BAV20WS-V-G | I <sub>R</sub>  |      |      | 15   | μΑ   |
|                            | V <sub>R</sub> = 200 V  | BAV21WS-V-G | I <sub>R</sub>  |      |      | 100  | nA   |
|                            | $V_R = 200 \text{ V}, T_j = 100 ^{\circ}\text{C}$                                     | BAV21WS-V-G | I <sub>R</sub>  |      |      | 15   | μΑ   |
| Dynamic forward resistance | I <sub>F</sub> = 10 mA  |             | r <sub>f</sub>  |      | 5    |      | Ω    |
| Diode capacitance          | V <sub>R</sub> = 0, f = 1 MHz   |             | C <sub>D</sub>  |      | 1.5  |      | pF   |
| Reverse recovery time      | $I_F = 30 \text{ mA}, I_R = 30 \text{ mA},$<br>$I_R = 3 \text{ mA}, R_L = 100 \Omega$ |             | t <sub>rr</sub> |      |      | 50   | ns   |

## **Typical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

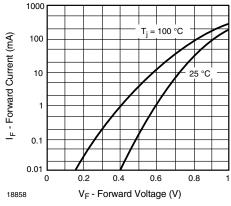


Figure 1. Forward Current vs. Forward Voltage

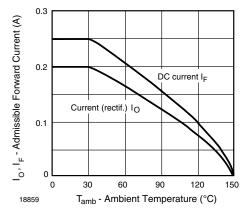


Figure 2. Admissible Forward Current vs. Ambient Temperature

<sup>1)</sup> Valid provided that leads are kept at ambient temperature

## **Vishay Semiconductors**

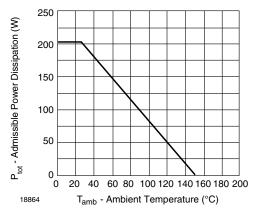


Figure 3. Admissible Power Dissipation vs. Ambient Temperature

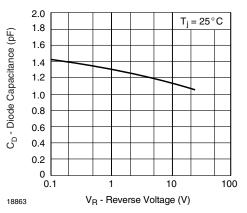


Figure 6. Capacitance vs. Reverse Voltage

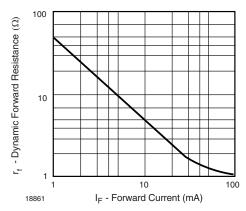


Figure 4. Dynamic Forward Resistance vs. Forward Current

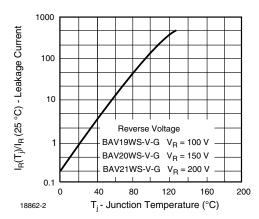


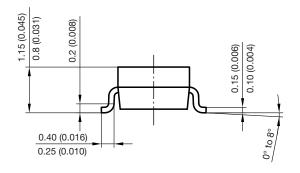
Figure 5. Leakage Current vs. Junction Temperature

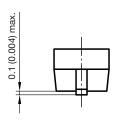
# BAV19WS-V-G, BAV20WS-V-G, BAV21WS-V-G

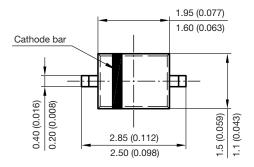
### **Vishay Semiconductors**



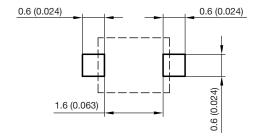
### Package Dimensions in millimeters (inches): SOD-323







Foot print recommendation:



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